NSN 5961-00-853-6629

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-853-6629 **Inclosure Material:** Glass **Overall Length:** 0.370 inches **Terminal Length:** 1.125 inches **Overall Diameter:** 0.200 inches **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 18.0 reverse voltage, peak **Current Rating Per Characteristic:** 5.00 amperes source cutoff current preset **Power Rating Per Characteristic:** 125.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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